

# VOLTAGE RANGE: 50 - 1000V

CURRENT: 2.0 A

## **Features**

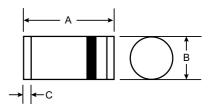
- **Diffused Junction**
- Low Forward Voltage Drop •
- **High Current Capability**
- **High Reliability** •
- High Surge Current Capability

#### **Mechanical Data**

- Case:LL41(DO-213AB)
- Terminals:Plated terminals, solderable per
- MIL-STD-202, Method 208
- Polarity:Red Color band on body denotes cathode
- Mounting position : Any
- Weight:0.12grams







LL41/ DO-213AB							
Dim	Min	Max					
Α	4.80	5.20					
В	2.40	2.60					
С	0.55 Nominal						
All Dimensions in mm							

## Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SM201	SM202	SM203	SM204	SM205	SM206	SM207	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) $@T_A = 75^{\circ}C$	lo	2.0						A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	70					A		
Forward Voltage $@I_F = 2.0A$	Vfm	1.0						V	
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	<b>I</b> RM	5.0 50						μA	
Typical Junction Capacitance (Note 2)	Cj	20					pF		
Typical Thermal Resistance Junction to Ambient (Note 1)	RθJA				40				K/W
Operating Temperature Range	Tj	-65 to +125					°C		
Storage Temperature Range	Tstg	-65 to +150					°C		

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.

SM201 - SM207

# SURFACE MOUNT SILICON RECTIFIER DIODES



